

# ABB 5SDD55L5500 Rectifier Diode datasheet

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Properties

Key Parameters

Industry standard housing

Suitable for parallel operation

High operating temperature

Low forward voltage drop

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# 5SDD 55L5500

## Rectifier Diode

### Properties

- Industry standard housing
- Suitable for parallel operation
- High operating temperature
- Low forward voltage drop

### Key Parameters

$V_{RSM}$	=	5 500	V
$I_{FAVm}$	=	5 372	A
$I_{FSM}$	=	67 500	A
$V_{TO}$	=	0.912	V
$r_T$	=	0.089	m $\Omega$

### Types

	$V_{RSM}$
<b>5SDD 55L5500</b>	<b>5 500 V</b>
Conditions:	$T_j = -40 \div 150 \text{ }^\circ\text{C}$ , half sine waveform, $f = 5 \text{ Hz}$ , note 1

### Mechanical Data

$F_m$	Mounting force	$70 \pm 7 \text{ kN}$
$m$	Weight	<b>1.45 kg</b>
$D_s$	Surface creepage distance	<b>40 mm</b>
$D_a$	Air strike distance	<b>20 mm</b>

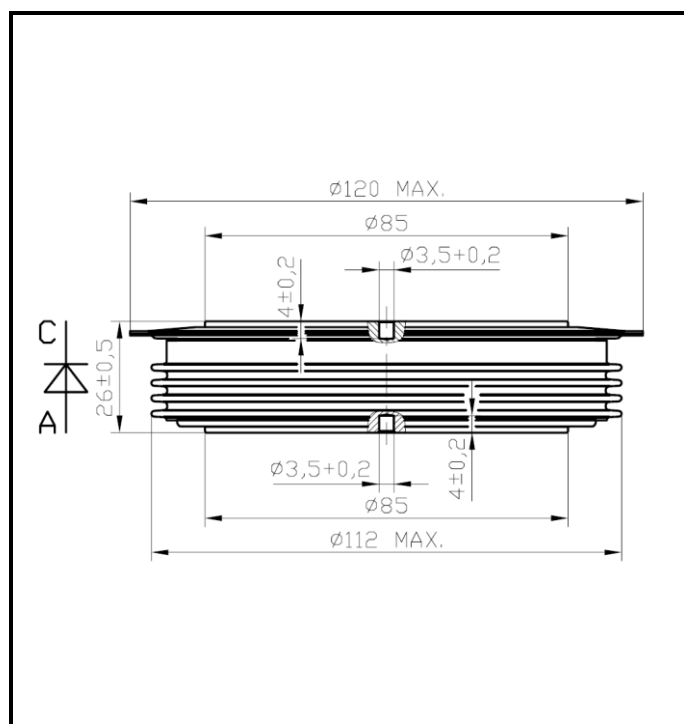


Fig. 1 Case



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<b>Maximum Ratings</b>		<b>Maximum Limits</b>	<b>Unit</b>	
$V_{RSM}$	<b>Non-repetitive peak reverse voltage</b> <i>half sine waveform, <math>f = 5</math> Hz, <math>t_p = 10</math>ms, note 1</i>	<b>5 500</b>	<b>V</b>	
$V_{RRM}$	<b>Repetitive peak reverse voltage</b> <i>half sine waveform, <math>f = 50</math> Hz, <math>t_p = 10</math>ms, note 1</i>	<b>5 000</b>	<b>V</b>	
$I_{FAVm}$	<b>Average forward current</b> $T_c = 85$ °C	<b>5 372</b>	<b>A</b>	
$I_{FRMS}$	<b>RMS forward current</b> $T_c = 85$ °C	<b>8 438</b>	<b>A</b>	
$I_{RRM}$	<b>Repetitive reverse current</b> $V_R = V_{RRM}$	<b>200</b>	<b>mA</b>	
$I_{FSM}$	<b>Non repetitive peak surge current</b> $V_R = 0$ V, <i>half sine pulse</i>	$t_p = 8.3$ ms	<b>72 100</b>	<b>A</b>
		$t_p = 10$ ms	<b>67 500</b>	<b>A</b>
$Pt$	<b>Limiting load integral</b> $V_R = 0$ V, <i>half sine pulse</i>	$t_p = 8.3$ ms	<b>21 577 000</b>	<b>A<sup>2</sup>s</b>
		$t_p = 10$ ms	<b>22 781 000</b>	<b>A<sup>2</sup>s</b>
$T_{jmin} - T_{jmax}$	<b>Operating temperature range</b>	<b>-40 ÷ 150</b>	<b>°C</b>	
$T_{STG}$	<b>Storage temperature range</b>	<b>-40 ÷ 150</b>	<b>°C</b>	

Unless otherwise specified  $T_j = 150$  °C

Note 1: De-rating factor of 0.13%  $V_{RRM}$  or  $V_{RSM}$  per °C is applicable for  $T_j$  below 25 °C

<b>Characteristics</b>		<b>Value</b>			<b>Unit</b>
		<b>min</b>	<b>typ</b>	<b>max</b>	
$V_{T0}$	<b>Threshold voltage</b>			<b>0.912</b>	<b>V</b>
$r_T$	<b>Forward slope resistance</b> $I_{F1} = 8\,600$ A, $I_{F2} = 25\,900$ A			<b>0.089</b>	<b>mΩ</b>
$V_{FM}$	<b>Maximum forward voltage</b> $I_{FM} = 5\,000$ A			<b>1.330</b>	<b>V</b>
$Q_{rr}$	<b>Recovered charge</b> $V_R = 100$ V, $I_{FM} = 2000$ A, $di_F/dt = -30$ A/μs		<b>5 500</b>		<b>μC</b>

Unless otherwise specified  $T_j = 150$  °C

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Thermal Parameters			Value	Unit
$R_{thjc}$	Thermal resistance junction to case	double side cooling	5.5	K/kW
		anode side cooling	10.5	
		cathode side cooling	11.5	
$R_{thch}$	Thermal resistance case to heatsink	double side cooling	1.5	K/kW
		single side cooling	3.0	

**Transient Thermal Impedance**

Analytical function for transient thermal impedance

$$Z_{thjc} = \sum_{i=1}^4 R_i (1 - \exp(-t / \tau_i))$$

Conditions:  
 $F_m = 70 \pm 7$  kN, Double side cooled

Correction for periodic waveforms

180° sine:	0.3 K/kW
120° sine:	0.4 K/kW
60° sine:	0.7 K/kW
180° rectangular:	0.3 K/kW
120° rectangular:	0.5 K/kW
60° rectangular:	0.9 K/kW

$i$	1	2	3	4
$\tau_i$ (s)	0.6754	0.1067	0.0165	0.0014
$R_i$ (K/kW)	3.715	1.438	0.229	0.100

Fig. 2 Dependence transient thermal impedance junction to case on square pulse

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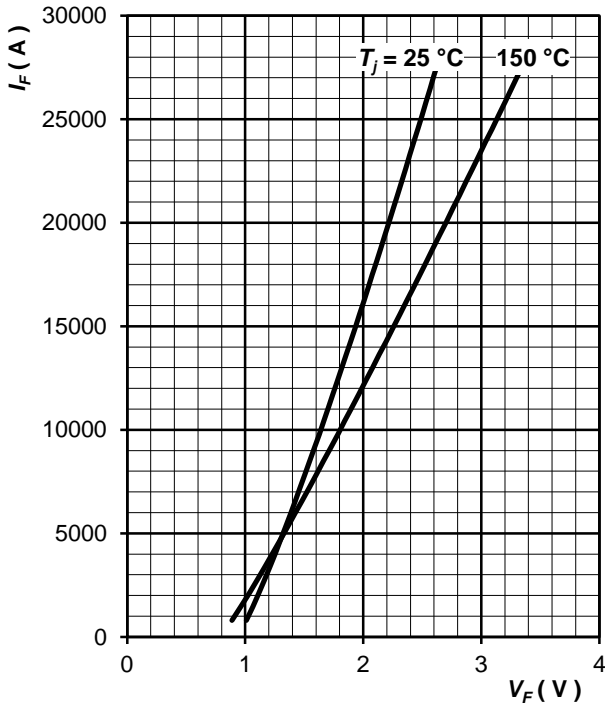


Fig. 3 Maximum forward voltage drop characteristics

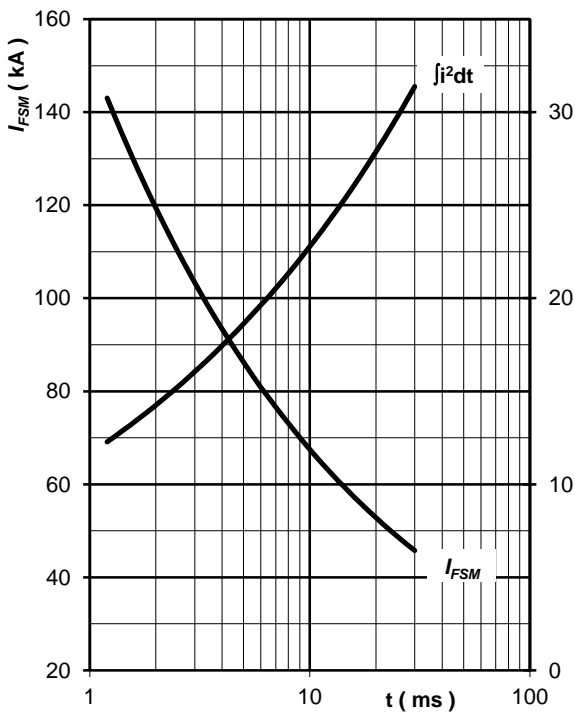


Fig. 4 Surge forward current vs. pulse length, half sine wave, single pulse,  $V_R = 0 \text{ V}$ ,  $T_j = T_{jmax}$

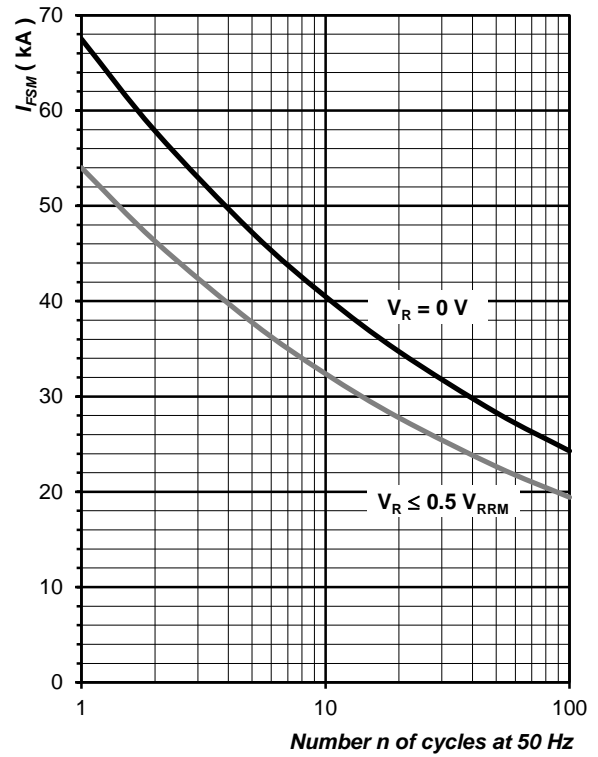


Fig. 5 Surge forward current vs. number of pulses, half sine wave,  $T_j = T_{jmax}$

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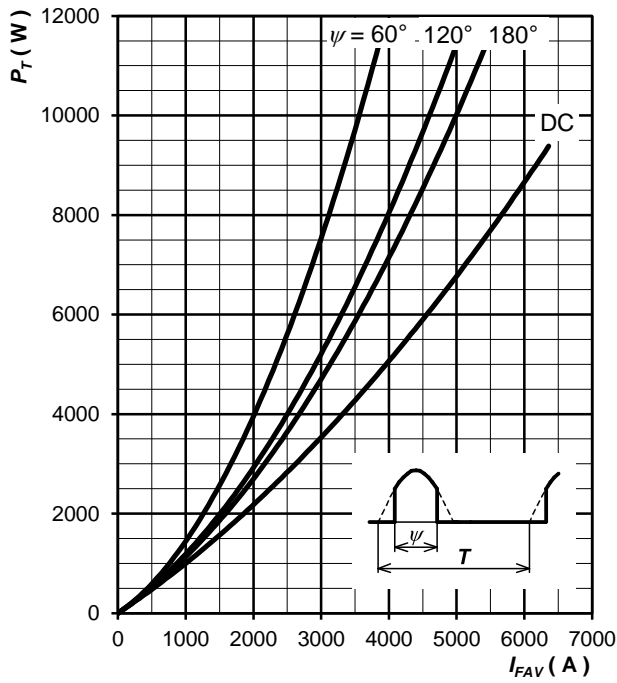


Fig. 6 Forward power loss vs. average forward current, sine waveform,  $f = 50 \text{ Hz}$ ,  $T = 1/f$

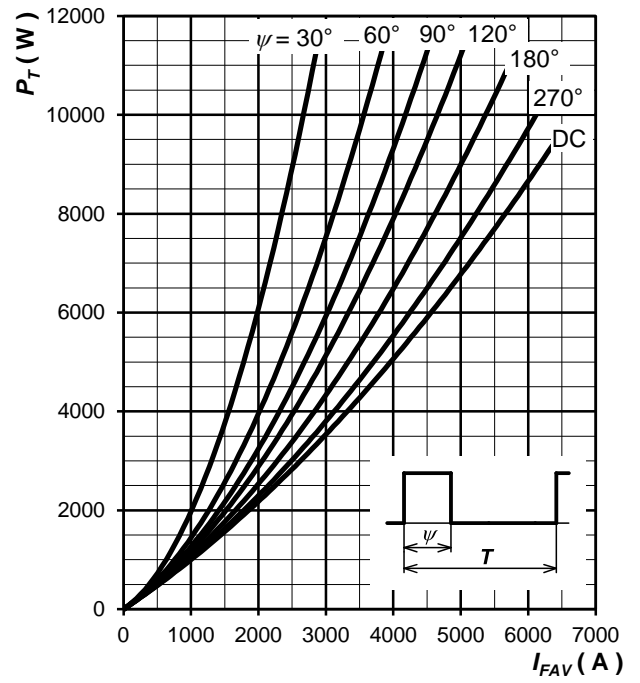


Fig. 7 Forward power loss vs. average forward current, square waveform,  $f = 50 \text{ Hz}$ ,  $T = 1/f$

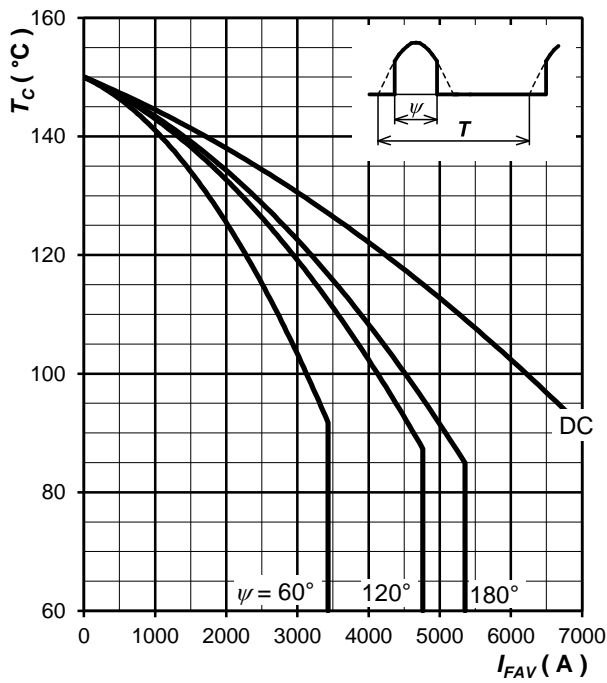


Fig. 8 Max. case temperature vs. aver. forward current, sine waveform,  $f = 50 \text{ Hz}$ ,  $T = 1/f$

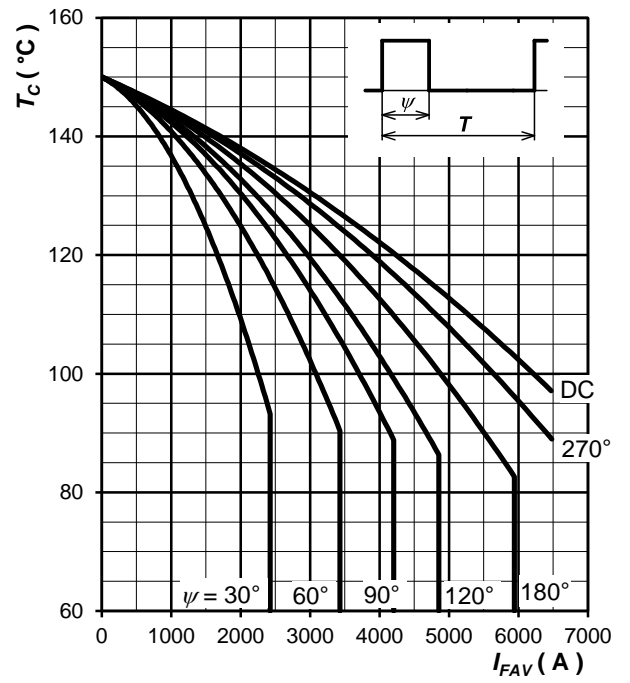


Fig. 9 Max. case temperature vs. aver. forward current, square waveform,  $f = 50 \text{ Hz}$ ,  $T = 1/f$

Notes:

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